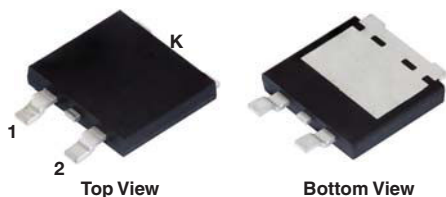


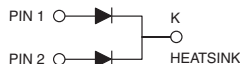
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.40\text{ V}$ at $I_F = 5\text{ A}$

TMBS® eSMP® Series
SMPD



V40D100C



FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
I_{FSM}	250 A
V_F at $I_F = 20\text{ A}$ ($T_A = 125\text{ °C}$)	0.63 V
T_J max.	150 °C

MECHANICAL DATA

Case: SMPD

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40D100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	40	A
		20	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	250	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.48	-	V
	I _F = 10 A			0.56	-	
	I _F = 20 A			0.71	0.75	
	I _F = 5 A	T _A = 125 °C		0.40	-	
	I _F = 10 A			0.51	-	
	I _F = 20 A			0.63	0.69	
Reverse current at rated V _R per diode	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	11	-	μA
		T _A = 125 °C		11	-	mA
	V _R = 100 V	T _A = 25 °C		-	1000	μA
		T _A = 125 °C		24	80	mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 5\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V40D100C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	1.9	$^{\circ}\text{C/W}$
	per device		1.0	
	per device	$R_{\theta JA}^{(1)(2)}$	45	

Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SMPD	V40D100C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel

RATINGS AND CHARACTERISTICS CURVES

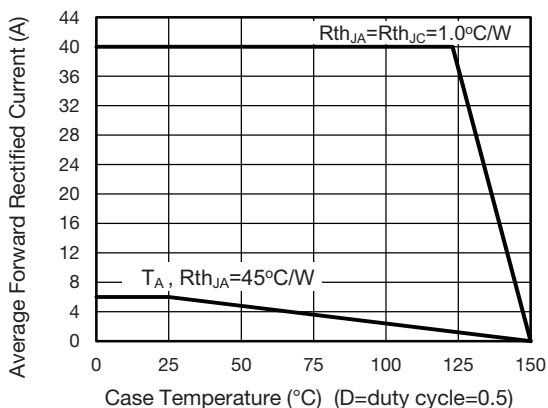
($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

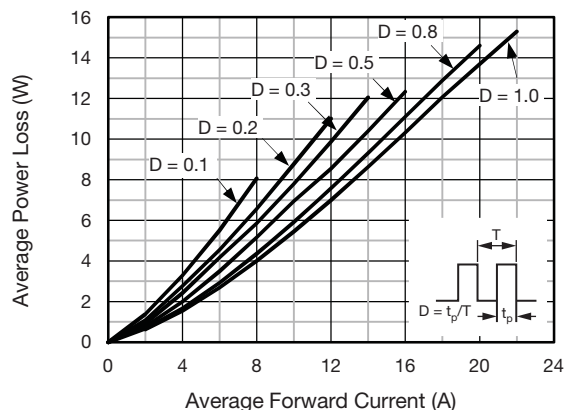


Fig. 2 - Forward Power Loss Characteristics Per Diode

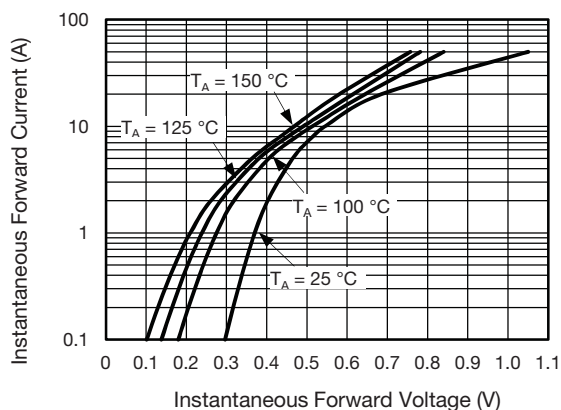


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

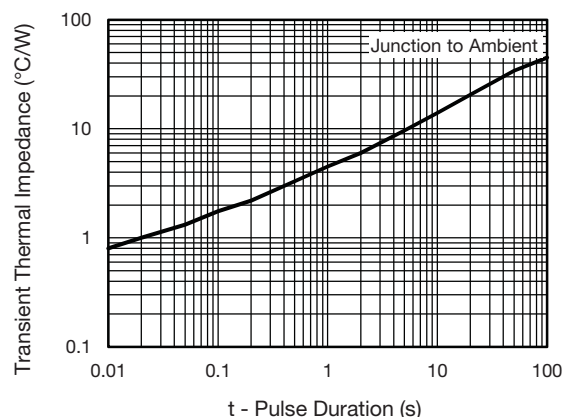


Fig. 6 - Typical Transient Thermal Impedance Per Device

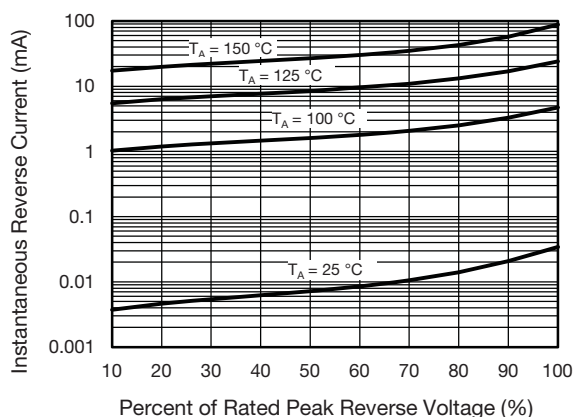


Fig. 4 - Typical Reverse Characteristics Per Diode

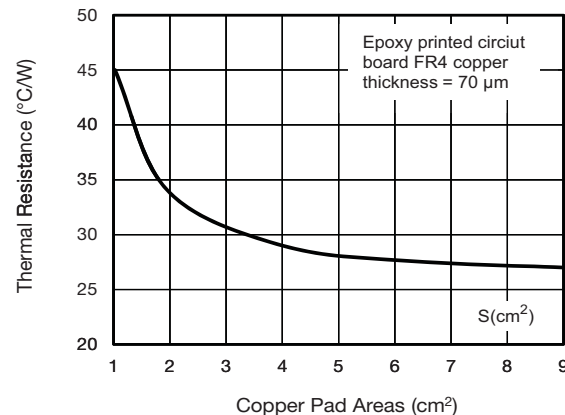


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

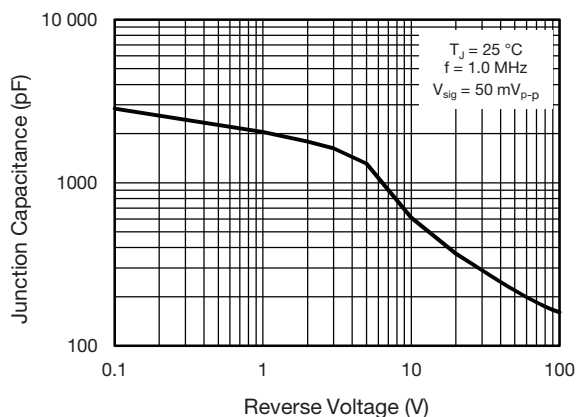
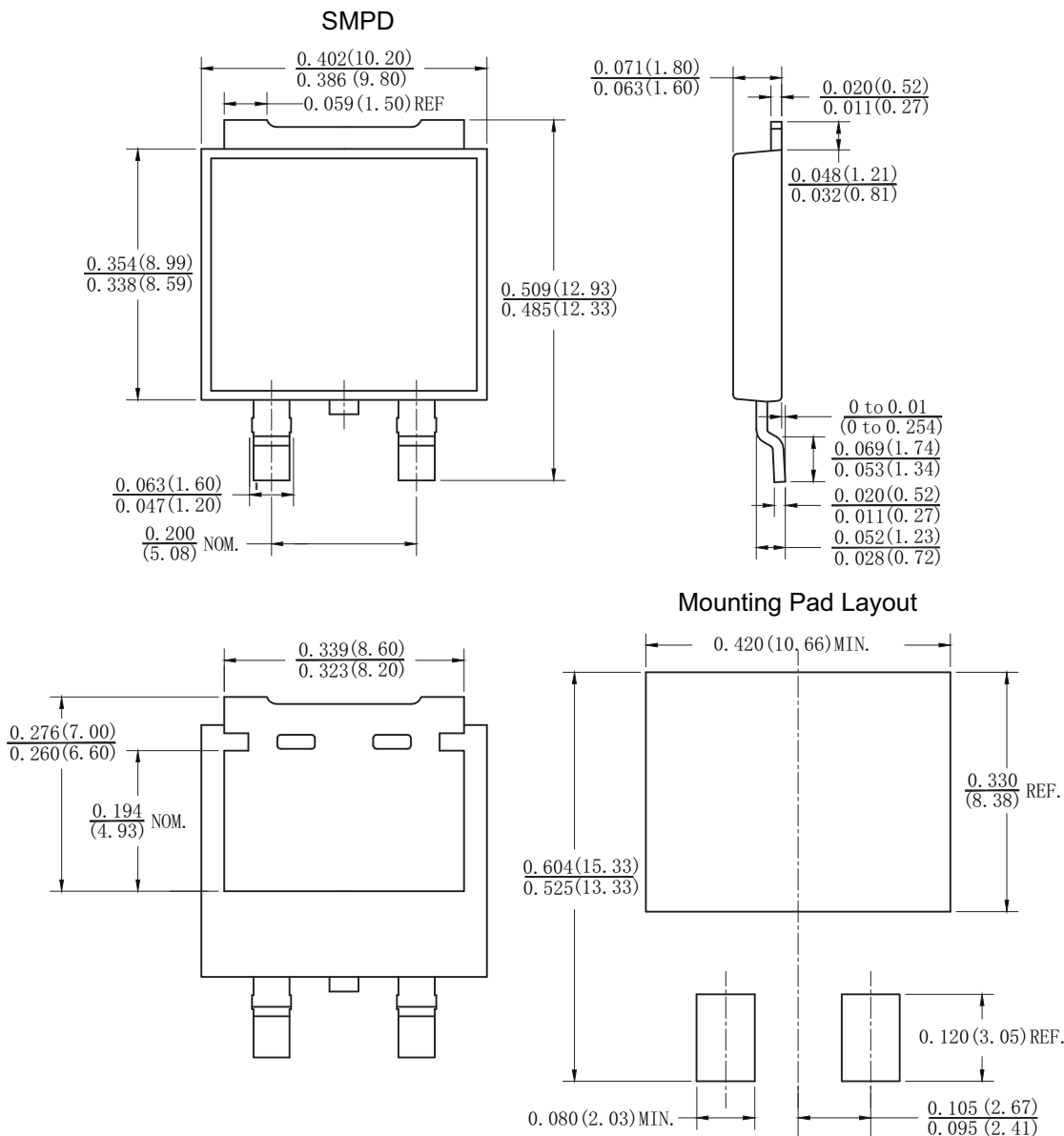


Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)




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